

FFSH20120ADN-F085

ABSOLUTE MAXIMUM RATINGS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit	
V_{RRM}	Peak Repetitive Reverse Voltage	1200	V	
E_{AS}	Single Pulse Avalanche Energy (Note 1)	100	mJ	
I_F	Continuous Rectified Forward Current @ $T_C < 155^\circ\text{C}$	10* / 20**	A	
	Continuous Rectified Forward Current @ $T_C < 135^\circ\text{C}$	15* / 30**		
$I_{F, Max}$	Non-Repetitive Peak Forward Surge Current	$T_C = 25^\circ\text{C}$, 10 μs	630	A
		$T_C = 150^\circ\text{C}$, 10 μs	560	A
$I_{F, SM}$	Non-Repetitive Forward Surge Current	Half-Sine Pulse, $t_p = 8.3$ ms	96	A
$I_{F, RM}$	Repetitive Forward Surge Current	Half-Sine Pulse, $t_p = 8.3$ ms	46	A
P_{tot}	Power Dissipation	$T_C = 25^\circ\text{C}$	150	W
		$T_C = 150^\circ\text{C}$	25	W
T_J, T_{STG}	Operating and Storage Temperature Range	-55 to +175	$^\circ\text{C}$	
	TO247 Mounting Torque, M3 Screw	60	Ncm	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. E_{AS} of 100 mJ is based on starting $T_J = 25^\circ\text{C}$, $L = 0.5$ mH, $I_{AS} = 20$ A, $V = 50$ V.

*Per leg, ** Per Device

THERMAL CHARACTERISTICS

Symbol	Parameter	Value	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max	1.0* / 0.44**	$^\circ\text{C}/\text{W}$

*Per leg, ** Per Device

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Test Condition	Min	Typ	Max	Unit
V_F	Forward Voltage	$I_F = 10$ A, $T_C = 25^\circ\text{C}$	-	1.45	1.75	V
		$I_F = 10$ A, $T_C = 125^\circ\text{C}$	-	1.7	2.0	
		$I_F = 10$ A, $T_C = 175^\circ\text{C}$	-	2.0	2.4	
I_R	Reverse Current	$V_R = 1200$ V, $T_C = 25^\circ\text{C}$	-	-	200	μA
		$V_R = 1200$ V, $T_C = 125^\circ\text{C}$	-	-	300	
		$V_R = 1200$ V, $T_C = 175^\circ\text{C}$	-	-	400	
Q_C	Total Capacitive Charge	$V = 800$ V	-	62	-	nC
C	Total Capacitance	$V_R = 1$ V, $f = 100$ kHz	-	612	-	pF
		$V_R = 400$ V, $f = 100$ kHz	-	58	-	
		$V_R = 800$ V, $f = 100$ kHz	-	47	-	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

ORDERING INFORMATION

Part Number	Top Marking	Package	Shipping
FFSH20120ADN-F085	FFSH20120ADN	TO-247-3LD (Pb-Free / Halogen Free)	30 Units / Tube

TYPICAL CHARACTERISTICS

($T_J = 25^\circ\text{C}$ unless otherwise noted; per leg)

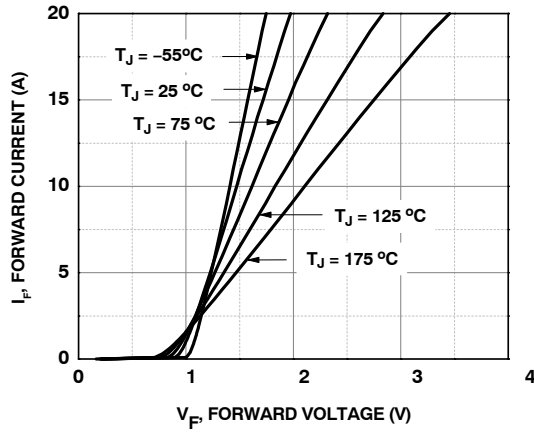


Figure 1. Forward Characteristics

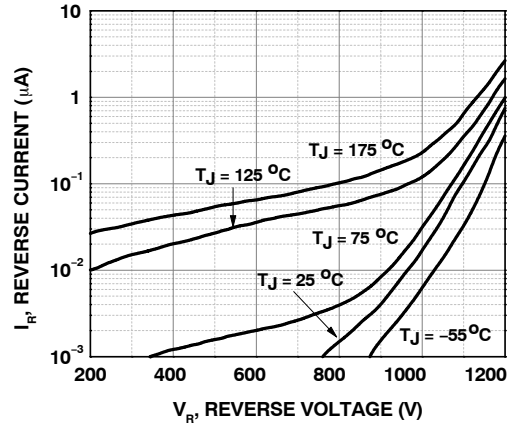


Figure 2. Reverse Characteristics

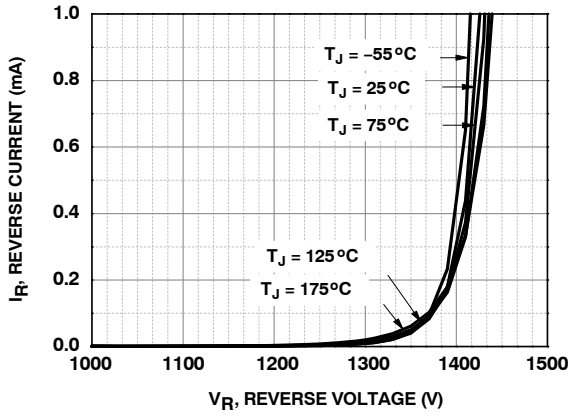


Figure 3. Reverse Characteristics

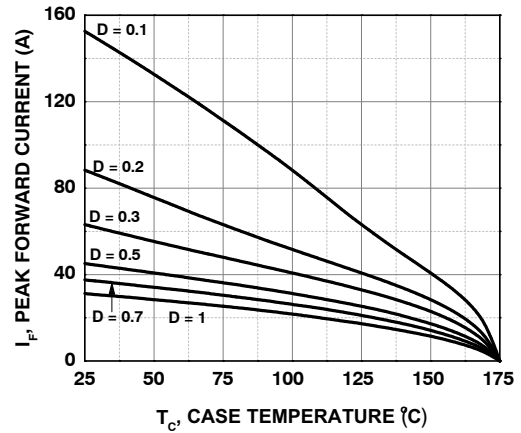


Figure 4. Current Derating

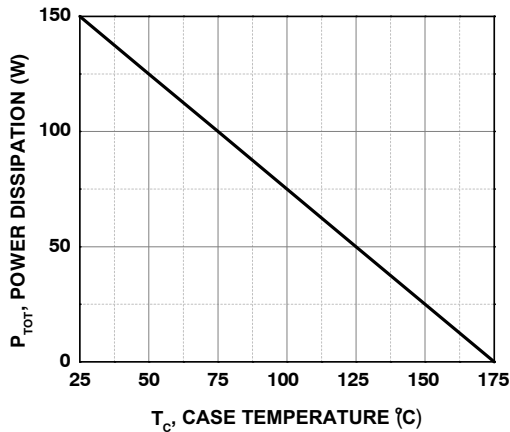


Figure 5. Power Derating

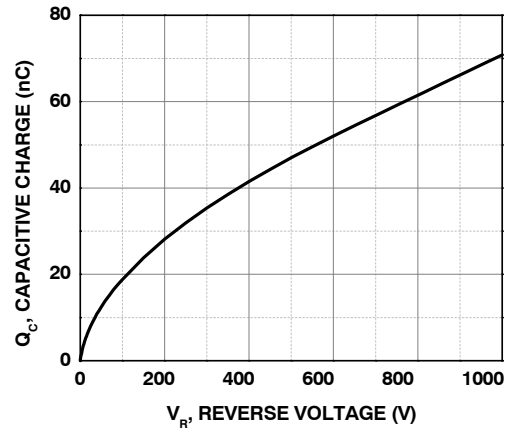


Figure 6. Capacitive Charge vs. Reverse Voltage

TYPICAL CHARACTERISTICS

(T_J = 25°C unless otherwise noted; per leg; continued)

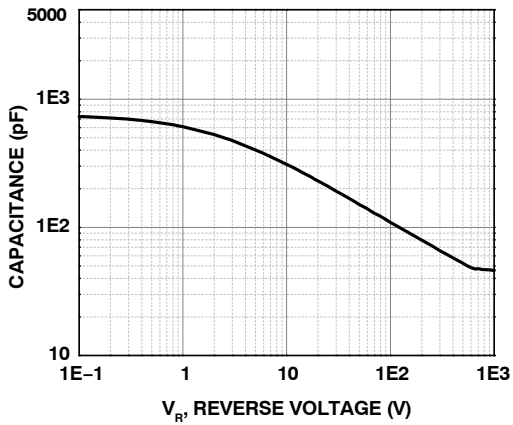


Figure 7. Capacitance vs. Reverse Voltage

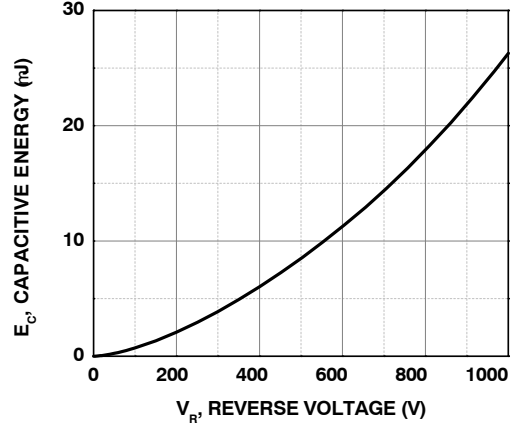


Figure 8. Capacitance Stored Energy

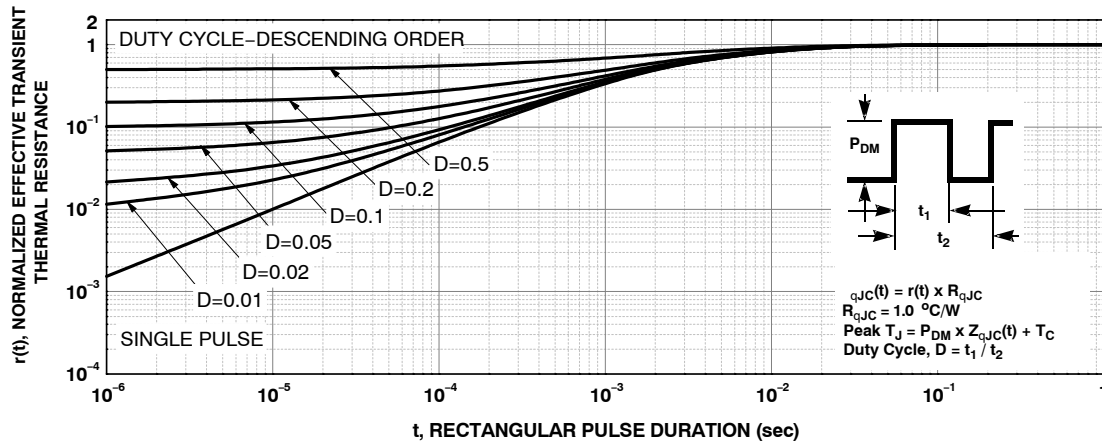


Figure 9. Junction-to-Case Transient Thermal Response Curve

TEST CIRCUIT AND WAVEFORMS

L = 0.5 mH
 R < 0.1 Ω
 V_{DD} = 50 V
 $E_{AVL} = 1/2LI^2 [V_{R(AVL)} / (V_{R(AVL)} - V_{DD})]$
 Q1 = IGBT (BV_{CES} > DUT V_{R(AVL)})

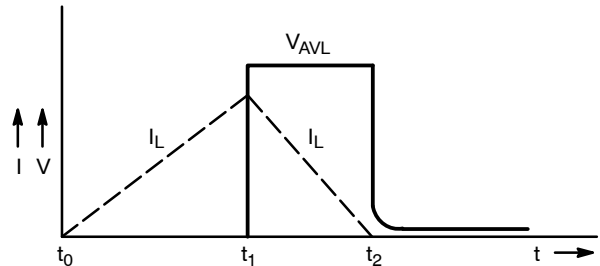
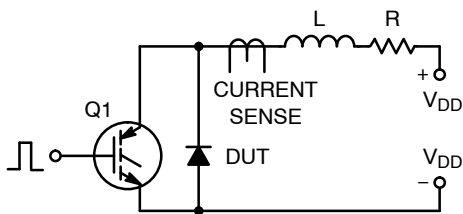


Figure 10. Unclamped Inductive Switching Test Circuit & Waveform

MECHANICAL CASE OUTLINE

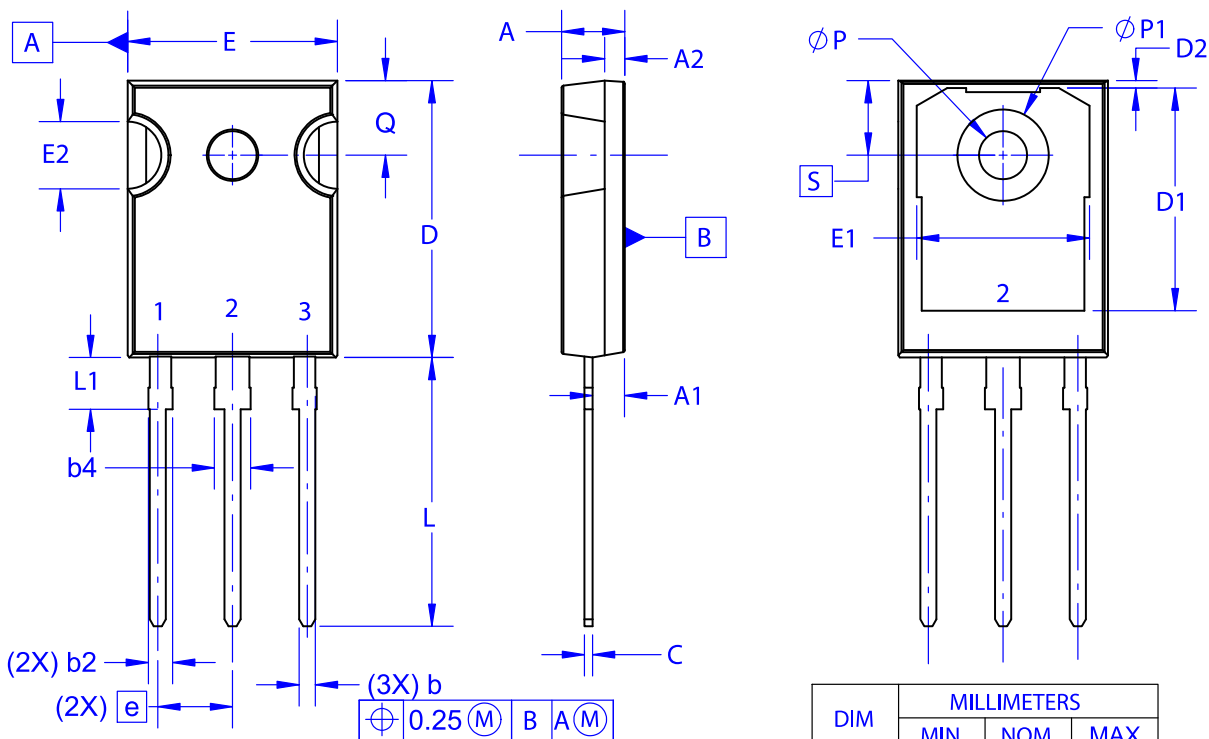
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ON Semiconductor®



TO-247-3LD
CASE 340CH
ISSUE A

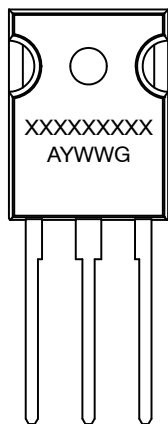
DATE 09 OCT 2019



NOTES: UNLESS OTHERWISE SPECIFIED.

- A. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
- B. ALL DIMENSIONS ARE IN MILLIMETERS.
- C. DRAWING CONFORMS TO ASME Y14.5 - 2009.
- D. DIMENSION A1 TO BE MEASURED IN THE REGION DEFINED BY L1.
- E. LEAD FINISH IS UNCONTROLLED IN THE REGION DEFINED BY L1.

GENERIC MARKING DIAGRAM*



XXXX = Specific Device Code
A = Assembly Location
Y = Year
WW = Work Week
G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

DIM	MILLIMETERS		
	MIN	NOM	MAX
A	4.58	4.70	4.82
A1	2.29	2.475	2.66
A2	1.40	1.50	1.60
D	20.32	20.57	20.82
E	15.37	15.62	15.87
E2	4.96	5.08	5.20
e	~	5.56	~
L	19.75	20.00	20.25
L1	3.69	3.81	3.93
∅P	3.51	3.58	3.65
Q	5.34	5.46	5.58
S	5.34	5.46	5.58
b	1.17	1.26	1.35
b2	1.53	1.65	1.77
b4	2.42	2.54	2.66
c	0.51	0.61	0.71
D1	13.08	~	~
D2	0.51	0.93	1.35
E1	12.81	~	~
∅P1	6.61	6.73	6.85

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